

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L51	0	(macros and voltage near4 generators and register and volatge near2 limiter and substrate near2 bias near3 generator and boosted near3 voltage near4 generator and negative near3 voltage near3 generator).clm.	US-PGPUB	OR	ON	2005/12/20 13:02
L52	0	(macros and voltage near4 generator and register and volatge near2 limiter and substrate near2 bias near3 generator and boosted near3 voltage near4 generator and negative near3 voltage near3 generator).clm.	US-PGPUB	OR	ON	2005/12/20 13:02

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	156042	(memory macro) near3 cells	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:39
L2	188769	(memory macro) near3 (cells arrays)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:39
L3	36697	(plurality plural multi multiple) near3 generators	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:44
L4	429	2 same 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:49
L5	2295	2 and 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:45
L6	99	5 and substrate near5 bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:50
L7	1	5 and Vpp and Vwl and Vbb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 10:51
L8	31	1 and Vpp and Vwl and Vbb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:06
L9	9	("4961007"   "4961167"   "5337284"   "5570005"   "5781481"   "5886932"   "5886942"   "5926427"   "6262934").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 10:54
L10	32	(memory DRAM) and Vpp and Vwl and Vbb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:02
L11	3	("5416434"   "5798961"   "5991990").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 11:08
L12	3	("6396324").URPN.	USPAT	OR	ON	2005/12/20 11:09

L13	5	("5008799"   "5301097"   "5388084"   "5412257"   "6052022").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 11:09
L14	10	("4439692"   "5072134"   "5180928"   "5184035"   "5247480"   "5253201"   "5255224"   "5267201"   "5268871"   "5276646").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 11:11
L15	15812	2 same (isolate isolating isolation seperating seperating seperate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:50
L16	105	3 and 15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:27
L17	7	("5063304"   "5300824"   "5777462"   "5966045"   "6205079"   "6313695"   "6366506").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 11:31
L18	23	("3762037"   "4799193"   "4992984"   "5025344"   "5134584"   "5235548"   "5235550"   "5255234"   "5262993"   "5295101"   "5349559"   "5384727"   "5396465"   "5400281"   "5406520"   "5412594"   "5412601"   "5424989"   "5428575"   "5615162"   "5673232"   "5761145"   "5787044").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/20 11:45
L19	8	("5946257").URPN.	USPAT	OR	ON	2005/12/20 11:49
L20	49746	("365").CLAS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 11:49
L21	34754	2 and 20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:50
L22	856	3 and 21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 11:50
L23	192	22 and (isolate isolating isolation seperating seperating seperate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:19
L24	25	20 and Vpp and Vwl and Vbb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:03
L25	15501	( substrate near2 bias or Vpp and negative near3 word or Vwl and boosted near3 word or Vbb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:18

L26	3841	2 and 25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:18
L27	158	3 and 26	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:19
L28	27720	( substrate near2 voltage or Vpp and negative near3 voltage or Vwl and boosted near3 voltage or Vbb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:25
L29	6673	2 and 28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:22
L30	228	3 and 29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:22
L31	98	30 and (isolate isolating isolation seperationg seperating seperate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:29
L32	89839	("361").CLAS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 12:26
L33	880	2 and 32	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:24
L34	10	3 and 33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:24
L35	66731	("327").CLAS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 12:24
L36	4852	2 and 35	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:29
L37	229	3 and 36	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:27

L38	60	37 and ( substrate near2 voltage or Vpp and negative near3 voltage or Vwl and boosted near3 voltage or Vbb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:25
L39	3107	(361/86,87,91.1,111).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 12:47
L40	68	2 and 39	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:27
L41	1	3 and 40	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:29
L42	6615	(365/200,226,227,229).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 12:29
L43	5219	2 and 42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:47
L44	178	3 and 43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:29
L45	52	44 and (isolate isolating isolation seperationg seperating seperate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:29
L46	1021	(361/18).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/12/20 12:47
L47	12	2 and 46	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/20 12:47